Solid state physics 2019 Final Exam April 16th, 2019

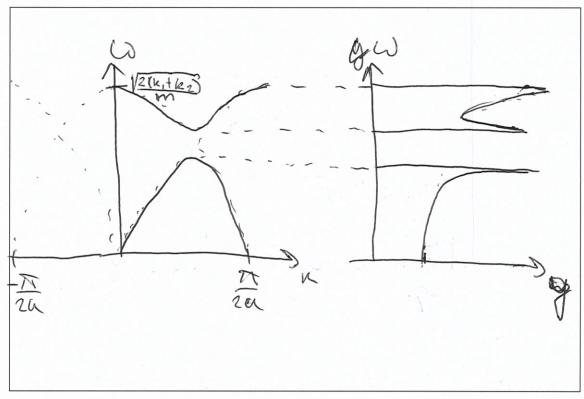
Good luck!

- You may not use textbooks, notes, or calculators.
- When plotting, label the axes and mark the important values.
- If you need extra answer space: ask for an extra exam copy, fill in your name and continue writing the solution.

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				~	a	→						
		0-	- ///-	- O-	- ///-	-0-	- ///-	- O-	- ///-			
		\check{m}	κ_2	\check{m}	κ_1	\check{m}	κ_2	\check{m}	κ_1			
(a)		s) Write do		quations	s of moti	on for a	toms in a	unit cel	l of this ch	ain using	the appropri	ate
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			(x,)		Kyt	Kz	eziko	······	k,-	K.)	
(b)	(10 poin	nts) Find th	he dispers	sion rela	ation by	solving	the equa	ations of	motion.			
		1 W2	: K	Cit.	Rz.	+	C14.	K. 2	RIK	<u> </u>		
	(5	solu	tion	0	f t	he	eid	gen	619	ble	-m)	
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1. (35 points) Band structure of phonons in 1D

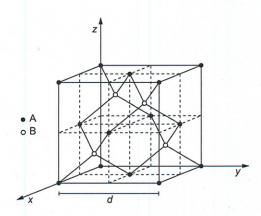
(c) (10 points) Sketch the dispersion relation $\omega(k)$ and the density of states $g(\omega)$ when $\kappa_1 \approx \kappa_2$.



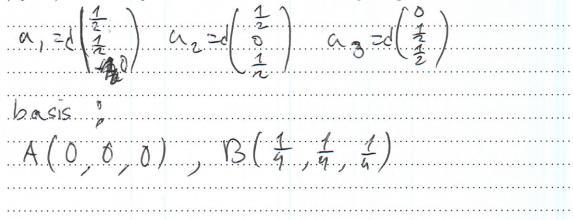
(d) (10 points) Simplify the found dispersion relation of the optical and acoustic branches assuming $\kappa_1 \gg \kappa_2$. How does this approximate dispersion of the acoustic branch relate to that of a monatomic chain with only one spring constant? How can the dispersion of the optical branch be understood from the vibrational frequency spectrum of a single diatomic molecule? (If you did not derive the dispersion, try to compute what happens when $\kappa_1 \gg \kappa_2$ directly.)

R, >> K2 Optical;
Optical:
mw2 = K, + k2 + lk, + K2 e 1 k2 2 kg
MW= Z K, + K2 + IK, + K2e 12 2hz
5) W= 12h, m, molecule with m, latoms of mass m, and spring k.
of mass m, and spring k.
acoustic
acoustici MW2 = K, + K2 - WII K, + K2 4020 MW2 = K, + K2 - WII K, + K2 4020
10 K1+ K2 - K1+ K2 (USZKO Z K, (1-(USZKO)
Was 2m and spring constan ke
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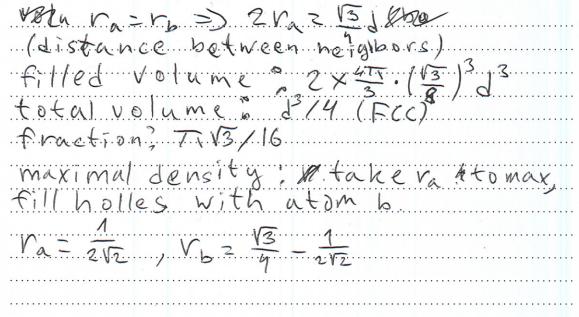
2. (30 points) Zinc-blende crystal structure



(a) (5 points) Give a set of primitive lattice vectors and the corresponding basis.



(b) (10 points) Calculate the filling fraction of this crystal, assuming that the atoms have equal radii $r_A = r_B$. For what ratio of r_B/r_A do you expect the filling fraction to be maximal?



(c)	(10 points) Calculate the reciprocal lattice vectors corresponding to the lattice vectors you formulated in (a). Calculate the volume of the primitive unit cell of the reciprocal lattice.
	12 volume: (275)3/(33/4)
	$b_{1} = \frac{417}{d} \begin{pmatrix} \frac{1}{2} \\ \frac{1}{2} \\ -\frac{1}{2} \end{pmatrix} \qquad b_{2} \geq \frac{477}{d} \begin{pmatrix} \frac{1}{2} \\ -\frac{1}{2} \\ \frac{1}{2} \end{pmatrix} \qquad b_{3} \geq \frac{477}{d} \begin{pmatrix} -\frac{1}{2} \\ \frac{1}{2} \\ \frac{1}{2} \end{pmatrix}$
	USEd: bcc primitive vectors
	······
	•••••••••••••••••••••••••••••••••••••••
(d)	(10 points) Compute the structure factor S corresponding to the lattice vectors found in (a). Use f_A and f_B as form factors for atoms A and B. Which diffraction peaks vanish when $f_A = f_B$?
(d)	and $f_{\rm B}$ as form factors for atoms A and B. Which diffraction peaks vanish when $f_{\rm A}=f_{\rm B}$?
(d)	and f_B as form factors for atoms A and B. Which diffraction peaks vanish when $f_A = f_B$? Sz. f_A t f_B e When $f_A \ge f_B$, $S \ge 0$ if f held f held f is a simple sequence.
(d)	and f_B as form factors for atoms A and B. Which diffraction peaks vanish when $f_A = f_B$? Solve $f_A = f_B$?
(d)	and f_B as form factors for atoms A and B. Which diffraction peaks vanish when $f_A = f_B$? Sz. f_A t f_B e When $f_A \ge f_B$, $S \ge 0$ if f held f held f is a simple sequence.
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3.	(35)	points)	\mathbf{A}	two-dimensional	semiconductor

Consider a 2D semiconductor with a band gap $E_G \gg k_B T$. The effective electron mass at the bottom of the conduction band is m_e . The effective hole mass at the top of the valence band is m_h , $m_h > m_e$. We put the zero of energy at the top of the valence band and consider the semiconductor to be in the intrinsic regime.

(a) (10 points) Compute and sketch the density of states of this semiconductor.

electrons; $g = 2 \times \sqrt{2} \times \frac{d \ln x}{d \ln x} \times \frac{d \ln x}{d \ln x} = \frac{m_e L^2}{\ln^2 x}$ $= \left(\frac{m_e}{\ln^2 x}\right) \times \left(2\pi k \times 2 \times \left(\frac{L}{2\pi}\right)^2\right) = \frac{m_e L^2}{\ln^2 x}$ $(ov \ Me \ per unit vol area),$ $f = \frac{m_e L^2}{\ln^2 x}$ $\int_{0}^{2\pi} \frac{d \ln x}{\ln x} d \ln x$ $\int_{0}^{2\pi} \frac{d \ln x}{\ln x} d \ln x$

(b) (10 points) Calculate the concentration of holes n_h in the valence band as a function of the Fermi energy E_F , temperature T, and m_h . Also calculate the concentration of electrons n_e in the conduction band as a function of the Fermi energy E_F , temperature T, and m_e .

Nh & Johne-leter) Bde =

similarly

no= pktace

(c)	(10 points) Write down an expression the electron heat capacity of this semiconductor as an integral over energies.
	C= d SEgel (EG-ED)BJE
	= SE(Ex-Ex)e (Ex-Ex)B 1 de
	+ same for holes
(d)	(5 points) Discuss whether the electron heat capacity becomes larger than the phonon heat capacity as
(4)	temperature is lowered towards 0K
	electron C, N e , bodecays exponentially.
	Phonon CNT2, sold.
	CPhonon & Celectron as D
	Celectron/Cphonon DO as T>O.

